

#### AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings of claims in the application:

#### LISTING OF CLAIMS:

1. (Canceled).

2. (Canceled).

3. (Canceled).

4. (Canceled).

5. (Currently Amended) Δ The scale as recited in claim 1 further comprising for technical devices which are used for high-resolution or ultrahigh-resolution imaging of structures, the scale comprising:

a plurality of one of crystalline and amorphous first material layers having a first thickness;

a plurality of one of crystalline and amorphous second material layers, the first material layers being different from the second material layers so that the second material layers are readily distinguishable from the first material layers when imaged using one of high-resolution and ultrahigh-resolution imaging methods, the second material layers having a second thickness and the first material layers alternating with the second material layers, at least one of the first and second material layers having a thickness of less than twenty-five nanometers, wherein the first and second material layers are deposited by a material deposition method in a deposition direction; and

a plurality of third material layers having a third thickness different from the second thickness and a plurality of fourth material layers having the same thickness as the first thickness, the third material layers alternating with the fourth material layers.

6. (Canceled).

7. (Currently Amended) Δ The scale as recited in claim 6 for technical devices which are used for high-resolution or ultrahigh-resolution imaging of structures, the scale comprising:

a plurality of one of crystalline and amorphous first material layers having a first thickness;

a plurality of one of crystalline and amorphous second material layers which are distinguishable from the first material layers when imaged using one of high-resolution and ultrahigh-resolution imaging methods, the second material layers having a second thickness and the first material layers alternating with the second material layers, both of the first and

second material layers having a thickness of less than ten nanometers, wherein the first material layers have a different strain than the second material layers, and the first and second materials layers have different band gaps; and

a plurality of third material layers having a third thickness different from the second thickness and a plurality of fourth material layers having the same thickness as the first thickness, the third material layers alternating with the fourth material layers.

8. (Canceled).

9. (Canceled).

10. (Canceled).

11. (Currently Amended) A The scale as recited in claim 8 for technical devices which are used for high-resolution or ultrahigh-resolution imaging of structures, the scale comprising:

a plurality of crystalline first material layers having a first thickness;

a plurality of amorphous second material layers which are distinguishable from the first material layers when imaged using one of high-resolution and ultrahigh-resolution imaging methods, the second material layers having a second thickness and the first material layers alternating with the second material layers, at least one of the first and second material layers having a thickness of less than twenty-five nanometers, the first material layers have a different composition than the second material layers; and

~~further comprising~~ a plurality of third material layers having a third thickness different from the second thickness and a plurality of fourth material layers having the same thickness as the first thickness, the third material layers alternating with the fourth material layers.

12. (Canceled).

13. (New) The scale as recited in claim 5 wherein the first material layers have a different strain than the second material layers.

14. (New) The scale as recited in claim 5 wherein both the first and second material layers have a thickness of fewer than ten nanometers.

15. (New) The scale as recited in claim 5 wherein the first and second materials layers have different band gaps.